VS-MBR1635-M3, VS-MBR1645-M3

Vishay Semiconductors

High Performance Schottky Rectifier, 16 A



www.vishay.com

O-220AC 2L	
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PRIMARY CHARACTERISTICS			
I _{F(AV)}	16 A		
V _R	35 V, 45 V		
V _F at I _F	0.57 V		
I _{RM} max.	40 mA at 125 °C		
T _J max.	150 °C		
E _{AS}	24 mJ		
Package	2L TO-220AC		
Circuit configuration	Single		

FEATURES

- 150 °C T_J operation
- · Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- · Guard ring for enhanced ruggedness and long term reliability
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

The VS-MBR16... Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS			
SYMBOL CHARACTERISTICS VALUES UNIT			UNITS
I _{F(AV)}	Rectangular waveform	16	А
V _{RRM}		35, 45	V
I _{FSM}	$t_p = 5 \ \mu s \ sine$	1800	А
V _F	16 A _{pk} , T _J = 125 °C	0.57	V
TJ	Range	-65 to +150	°C

VOLTAGE RATINGS				
PARAMETER	SYMBOL	VS-MBR1635-M3	VS-MBR1645-M3	UNITS
Maximum DC reverse voltage	V _R	35	45	M
Maximum working peak reverse voltage	V _{RWM}		40	v

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CON	TEST CONDITIONS V		UNITS
Maximum average forward current	I _{F(AV)}	T_{C} = 134 °C, rated V_{R}		16	А
Non-repetitive peak surge current	I _{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V _{RRM} applied	1800	А
		Surge applied at rated load of single phase, 60 Hz	condition half wave	150	
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 \text{ °C}, I_{AS} = 3.6 \text{ A}, L = 3.7 \text{ mH}$		24	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical 3.6		А	

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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS VALUES UNIT		UNITS	
Maximum forward voltage drop	V _{FM} ⁽¹⁾	V _{FM} ⁽¹⁾ 16 A	T _J = 25 °C	0.63	V
Maximum forward voltage drop			T _J = 125 °C	0.57	
Maximum instantaneous reverse current	rrent I _{RM} ⁽¹⁾	T _J = 25 °C	- Rated DC voltage	0.2	mA
Maximum instantaneous reverse current		T _J = 125 °C		40	
Maximum junction capacitance	CT	$V_{R} = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C 1400		1400	pF
Typical series inductance	L _S	Measured from top of terminal to mounting plane 8.0		nH	
Maximum voltage rate of change	dV/dt	Rated V _R 10 000 V/µ		V/µs	

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction temperature range	TJ		-65 to +150	ŝ	
Maximum storage temperature range	T _{Stg}		-65 to +175	°C	
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	1.50	°C 111	
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased	0.50	°C/W	
Approximate weight			2	g	
Approximate weight			0.07	oz.	
Mounting torque			6 (5)	kgf ⋅ cm	
Mounting torque maximum			12 (10)	(lbf · in)	
Mandalana daribar			MBR	1635	
Marking device		Case style 2L TO-220AC (JEDEC)	MBR	1645	



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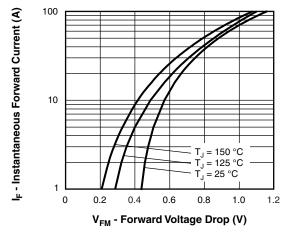


Fig. 1 - Maximum Forward Voltage Drop Characteristics

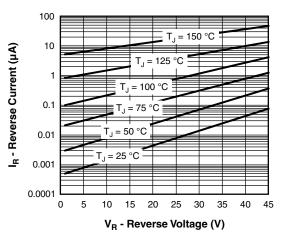


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

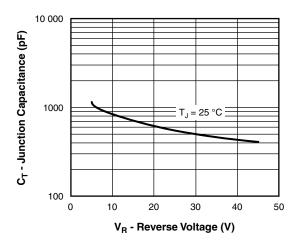


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

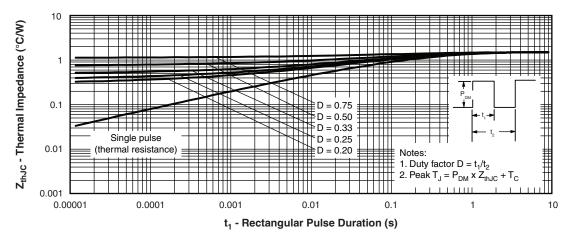
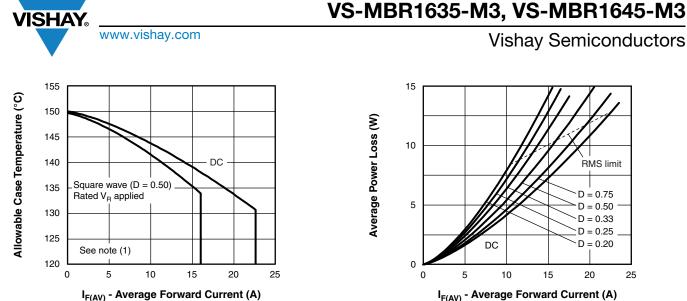
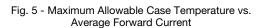


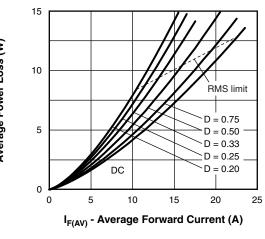
Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

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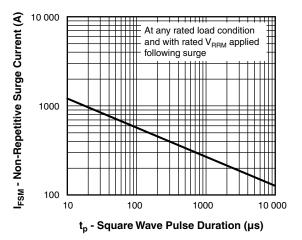


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

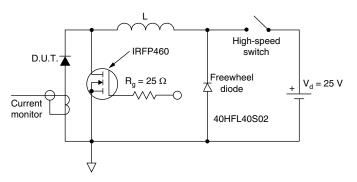


Fig. 8 - Unclamped Inductive Test Circuit

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})} / \mathsf{D}) \ (\mathsf{see fig. 6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \ \mathsf{applied} \\ \end{array}$

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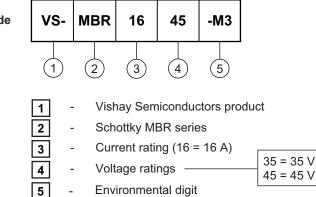
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ORDERING INFORMATION TABLE

Device code



-M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION (Example)				
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION		
VS-MBR1635-M3	50	Antistatic plastic tubes		
VS-MBR1645-M3	50	Antistatic plastic tubes		

LINKS TO RELATED DOCUMENTS					
Dimensions www.vishay.com/doc?96156					
Part marking information	www.vishay.com/doc?95391				



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